

# Medium Power Transistor

## 2SA1036K

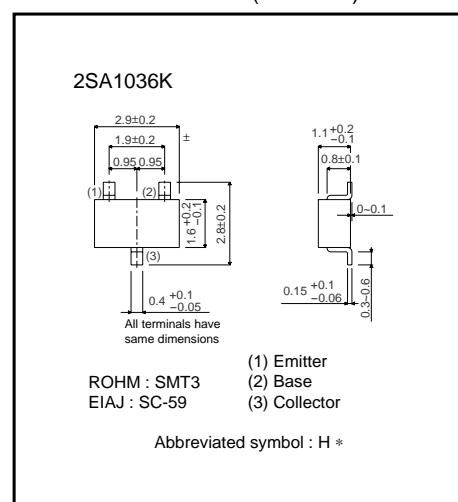
### ●Features

- 1) Large  $I_C$ .  
 $I_{C\text{MAX.}} = -500\text{mA}$
- 2) Low  $V_{CE(\text{sat.})}$ . Ideal for low-voltage operation.
- 3) Complements the 2SC2411K.

### ●Structure

Epitaxial planer type  
PNP silicon transistor

### ●External dimensions (Unit : mm)



\* Denotes  $h_{FE}$

### ●Absolute maximum ratings ( $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CB0}$	-40	V
Collector-emitter voltage	$V_{CE0}$	-32	V
Emitter-base voltage	$V_{EB0}$	-5	V
Collector current	$I_C$	-0.5	A *
Collector power dissipation	$P_C$	0.2	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

\*  $P_{C\text{MAX.}}$  must not be exceeded.

## Transistors

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	-40	-	-	V	$I_C = -100\mu A$
Collector-emitter breakdown voltage	$BV_{CEO}$	-32	-	-	V	$I_C = -1mA$
Emitter-base breakdown voltage	$BV_{EBO}$	-5	-	-	V	$I_E = -100\mu A$
Collector cutoff current	$I_{CBO}$	-	-	-1	$\mu A$	$V_{CB} = -20V$
Emitter cutoff current	$I_{EBO}$	-	-	-1	$\mu A$	$V_{EB} = -4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-	-0.6	V	$I_C/I_B = -300mA/-30mA$
DC current transfer ratio	$h_{FE}$	82	-	390	-	$V_{CE} = -3V, I_C = -100mA$
Transition frequency	$f_T$	-	200	-	MHz	$V_{CE} = -5V, I_E = 20mA, f = 100MHz$
Output capacitance	$C_{ob}$	-	7	-	pF	$V_{CB} = -10V, I_E = 0A, f = 1MHz$

## ●Packaging specifications

Type	$h_{FE}$	Package	Taping
		Code	T146
		Basic ordering unit (pieces)	3000
2SA1036K	PQR		○

$h_{FE}$  values are classified as follows.

Item	P	Q	R
$h_{FE}$	82 to 180	120 to 270	180 to 390

## ●Electrical characteristic curves

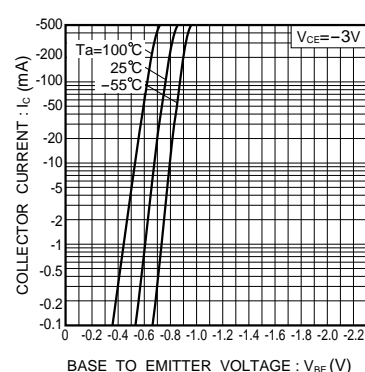


Fig.1 Grounded emitter propagation

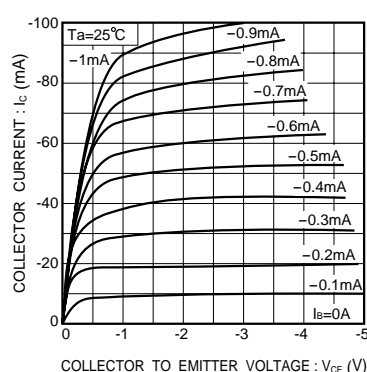


Fig.2 Grounded emitter output characteristics (I)

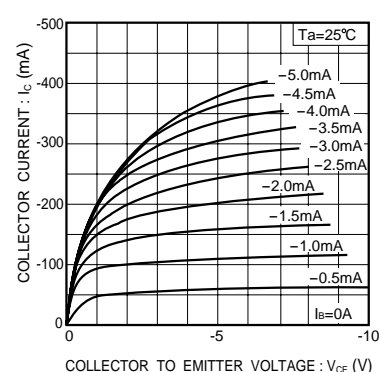


Fig.3 Ground emitter output characteristics (II)

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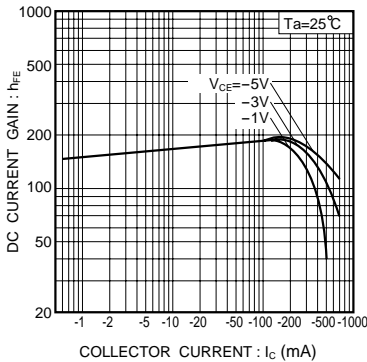


Fig.4 DC current gain vs. collector current (I)

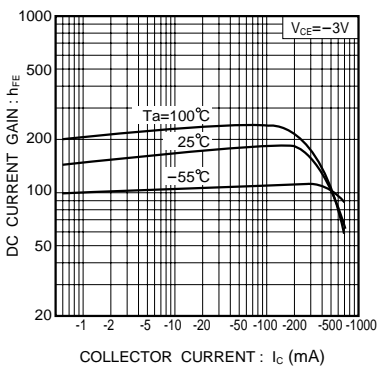


Fig.5 DC current gain vs. collector current (II)

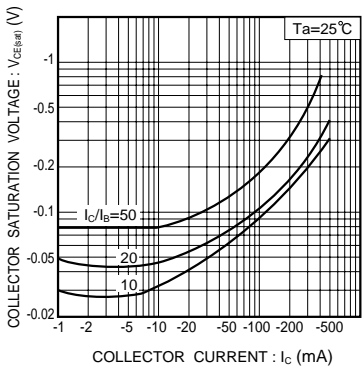


Fig.6 Collector emitter saturation voltage vs. collector current (I)

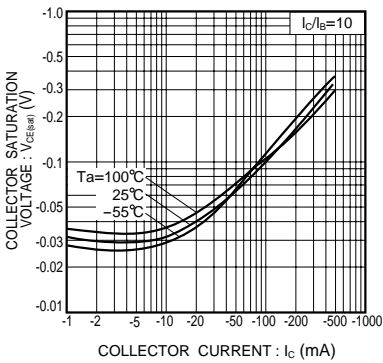


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

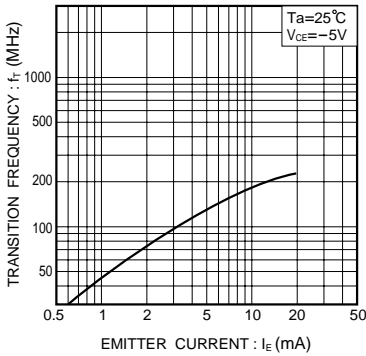


Fig.8 Gain bandwidth product vs. emitter current

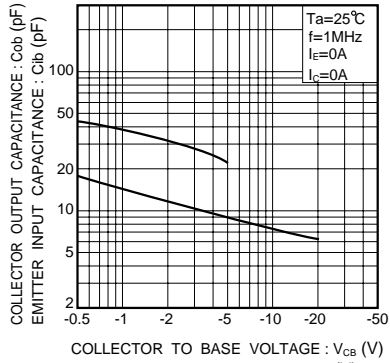


Fig.9 Collector output capacitance vs. collector-base voltage. Emitter input capacitance vs. emitter-base voltage

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